FJC1308



SEMICONDUCTOR®

FJC1308

Audio Power Amplifier Applications

- Complement to FJC1963
- High Collector Current
- Low Collector-Emitter Saturation Voltage



1. Base 2. Collector 3. Emitter

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_{C}=25^{\circ}C$ unless otherwise noted

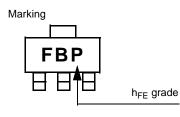
Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	-30	V
V _{CEO}	Collector-Emitter Voltage	-30	V
V _{EBO}	Emitter-Base Voltage	-6	V
I _C	Collector Current (DC)	-3	А
P _C	Power Dissipation(T _C =25°C)	0.5	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

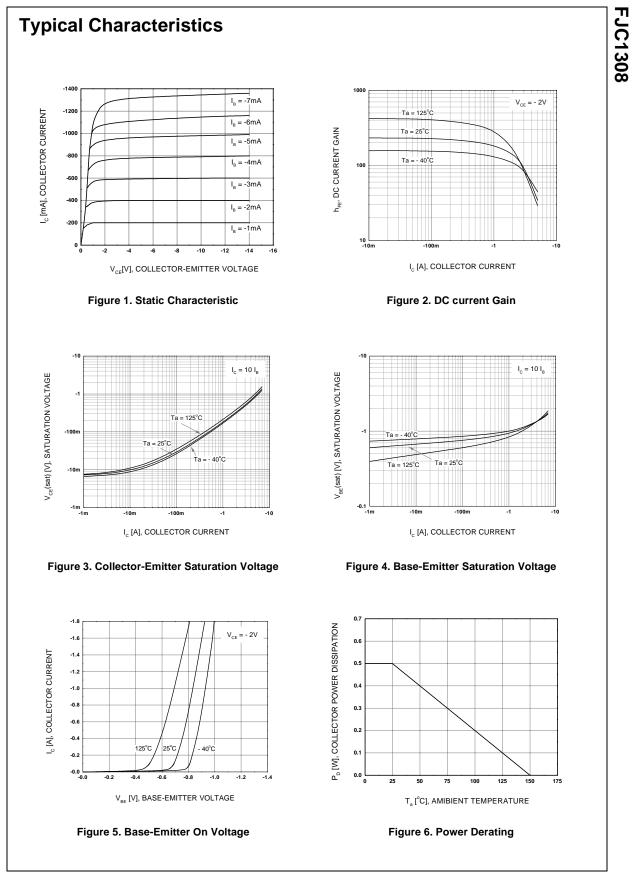
Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

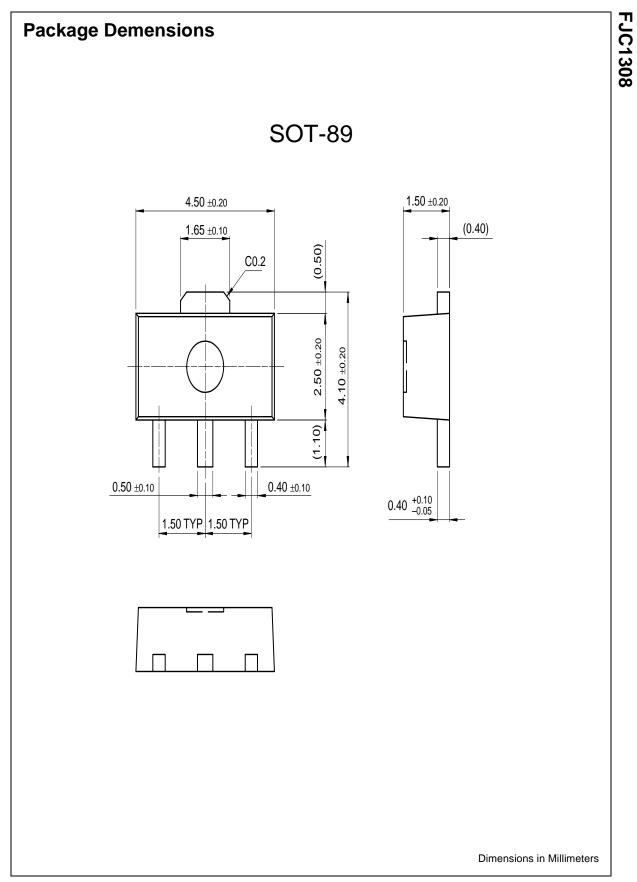
Symbol	Parameter	Test Condition	Min. Typ.		Max.	Units	
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =-50μA, I _E =0	-30			V	
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =-1mA, I _B =0	-30			V	
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =-50μA, I _C =0	-6			V	
I _{CEO}	Collector Cut-off Current	V _{CE} =-20V, V _B =0			-0.5	μA	
I _{EBO}	Emitter Cut-off Current	V _{EB} =-5V, I _C =0			-0.5	μΑ	
h _{FE}	DC Current Gain	V _{CE} =-2V, I _C =-0.5A	80		390		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =-1.5, I _B =-0.15A			-0.45	V	
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =-1.5, I _B =-0.15A			-1.5	V	

h_{FE} Classification

Classification	Р	Q	R
h _{FE}	80 ~ 180	120 ~ 270	180 ~ 390







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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
FJC1308PTF	Full Production	\$0.208	<u>SOT-89</u>	3	TAPE REEL
FJC1308QTF	Full Production	\$0.208	<u>SOT-89</u>	3	TAPE REEL
FJC1308RTF	Full Production	\$0.208	<u>SOT-89</u>	3	TAPE REEL

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